PCN Nun	nhori												
	PCN Number: 20200929000.2 PCN Date: Oct. 6, 2020												
Title:	Qualification of MIHO8 as additional Wafer Fab Site option and Leadframe finish characteristics  for select ABCD05HV devices						dframe finish chang						
<b>Customer Contact:</b>				PCN N	<u>Manage</u>	<u>er</u>		Dept:			Quality Services		
Proposed 1 <sup>st</sup> Ship Date:			e:	Apr. 6, 2021			Estimated Sample Availability:				Date provided at sample request.		
Change 1	Type:												
Asse	Assembly Site			Assembly Process							Assembly Materials		
Design						al Specifica					Mechanical Specification		
Test Site				Packing/Shipping/La							Test Process		
Wafer Bump Site				Wafer Bump Material							Wafer Bump Process		
				Wafer Fab Materials			Waf	Wafer Fab Process					
			Part number change										
					F	PCN Deta	ils						
Descript	ion of Cl	hange	:										
Texas Instruments is pleased to announce the qualification of its MIHO8 as additional fabrication facility and Leadframe finish change for the selected devices listed in the "Product Affected" section  Wafer Fab change:  Current Fab Site  Additional Fab Site													
					<b>147</b> 6	•							
	Current Fab Site		cess		Wafer iamet		litional b Site	'	Proc	ess	Wafer Diameter		
MAINE		ABCD	05HV		200 mn					BCD05HV 200			
	ame finisl	n (		ا ve Ro		double side	e)	(Sin	N	opos IiPdA Side F			
Leadfra  Qual deta  Reason f	ame finisl	n (		ا ve Ro	NiPdAu oughen	double side	e)	(Sin	N	liPdA	u		
Qual deta	ame finisl ails are pr	rovided		ا ve Ro	NiPdAu oughen	double side	2)	(Sin	N	liPdA	u		
Qual deta Reason f Continuity Anticipat	ame finish hils are pr for Chan y of Supp	rovided	I in the	re Ro Qual	NiPdAu oughen Data S	double side			gle S	liPdA Side F	u		
Qual deta Reason f Continuity Anticipat None	ame finish hils are pr for Chan y of Supp ted impa	rovided ge: oly act on	Form,	Qual	NiPdAu oughen Data S	double side			gle S	liPdA Side F	u Roughen)		
Qual deta Reason f Continuity Anticipat	ame finish hils are pr for Chan y of Supp ted impa	rovided ge: oly act on	Form,	Qual	NiPdAu oughen Data S	double side			gle S	liPdA Side F	u Roughen)		
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Sample product shipping label (not actual product label)

TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 2Q:

MSL 2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

OPT: ITEM: (L)T0:3750 5A LBL:



(1P) SN74LS07NSR (Q) 2000 (D) 0336 31T)LOT: 3959047MLA 4W) TKY(1T) 7523483812

(V) 0033317 (21L) CCO:USA (23L) ACO: MYS (20L) CSO: SHE (22L) ASO: MLA 23L) ACO: MYS

# **Product Affected:**

TPS92661QPHPRQ1

# **Automotive New Product Qualification Summary**

(As per AEC-Q100 and JEDEC Guidelines)

# Approve Date 11-August-2020

#### Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

					Data Displayed as. No	imber of lots / Total	sample size / Total falled		
Туре	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: TP\$92661QPHPRQ1	QBS Process Reference: LM25117QPMHX/NOPB	QBS Process Reference TCAN1042HVDRQ1
Test Group	A – A	ccelerated Environmer	it Stres	s Test	S				
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0	3/231/0
AC	A3	JEDEC JESD22- A102	3	77	Autoclave 121C	96 Hours	-	3/231/0	3/231/0
TC	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle, -65/150C	500 Cycles	-	3/231/0	3/231/0
TC-BP	A4	MIL-STD883 Method 2011	1	30	Post Temp. Cycle Bond Pull	Wires	-	1/30/0	1/30/0
PTC	A5	JEDEC JESD22- A105	1	45	Power Temperature Cycle	1000 Cycles	-	N/A	NA
HTSL	A6	JEDEC JESD22- A103	1	45	High Temp. Storage Bake, 150C	1000 Hours	-	1/45/0	1/45/0
Test Group	B – A	ccelerated Lifetime Sin	nulatio	n Tests					
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test, 125C	1000 Hours	-	3/231/1 (Note 1)	3/231/0
ELFR	B2	AEC Q100-008	3	800	Early Life Failure Rate, 150C	24 Hours	-	-	3/2400/0
EDR	В3	AEC Q100-005	3	77	NVM Endurance, Data Retention, and Operational Life	-	-	N/A	N/A
Test Group	C – Pa	ackage Assembly Integ	rity Te	sts					
WBS	C1	AEC Q100-001	1	30	Bond Shear (Cpk>1.67)	Wires	-	1/30/0	1/30/0
WBP	C2	MIL-STD883 Method 2011	1	30	Bond Pull (Cpk>1.67)	Wires	-	1/30/0	1/30/0
SD	C3	JEDEC JESD22- B102	1	15	Solderability (>95% Lead Coverage)	Pb & Pb-Free	-	N/A	N/A
PD	C4	JEDEC JESD22- B100 and B108	3	10	Physical Dimensions (Cpk>1.67)	-	-	N/A	N/A
Toot Crown	• D D	ie Fabrication Reliabili	tu Toot	•					
rest Group	ט – ט ע	ie rabilication Keliabili	ty rest	5			Completed Per Process	Completed Per Process	Completed Per Process
EM	D1	JESD61	-	-	Electromigration		Technology Requirements	Technology Requirements	Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependant Dielectric Breakdown		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
HCI	D3	JESD60 & 28	-	-	Hot Injection Carrier		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
		lectrical Verification Te	_						
HBM	E2	AEC Q100-002	1	3	ESD - HBM	2000 V	1/3/0	1/3/0	1/3/0
CDM	E3	AEC Q100-011	1	3	ESD - CDM	750 V	1/3/0	1/3/0	1/3/0
LU	E4	AEC Q100-004	1	6	Latch-up	(Per AEC Q100-004)	1/6/0	1/6/0	1/6/0
ED	E5	AEC Q100-009	3	30	Electrical Distributions	Cpk>1.67 Room, Hot, & Cold Test	1/30/0	3/90/0	3/90/0

Qual Device TPS92661QPHPRQ1 is qualified at LEVEL2-260C

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C Grade 1 (or Q): -40°C to +125°C Grade 2 (or T): -40°C to +105°C Grade 3 (or I): -40°C to +85°C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED
Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU Room: AC/uHAST

Qualified Pb-Free(SMT) and Green

Note 1: 1 discounted fail that occurred at 168 hrs has been attributed to EOS most likely caused by handling issues. FA report attached to eQDB

For questions regarding this notice, e-mails can be sent to the regional contacts shown below, or you can contact your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
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